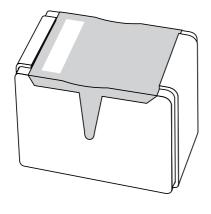
DISCRETE SEMICONDUCTORS

DATA SHEET



BAT254Schottky barrier diode

Product data sheet Supersedes data of 1999 Apr 22 2002 May 28



Schottky barrier diode

BAT254

FEATURES

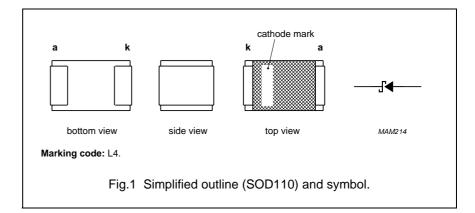
- Low forward voltage
- · Guard ring protected
- Very small ceramic SMD package.

APPLICATIONS

- Ultra high-speed switching
- Voltage clamping
- · Protection circuits
- Blocking diodes.

DESCRIPTION

Planar Schottky barrier diode encapsulated in a SOD110 very small ceramic SMD package.



LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|------------------|-------------------------------------|---|------|------|------|
| V _R | continuous reverse voltage | | _ | 30 | V |
| I _F | continuous forward current | | - | 200 | mA |
| I _{FRM} | repetitive peak forward current | $t_p \le 1 \text{ s}; \ \delta \le 0.5$ | - | 300 | mA |
| I _{FSM} | non-repetitive peak forward current | t _p < 10 ms | _ | 600 | mA |
| T _{stg} | storage temperature | | -65 | +150 | °C |
| T _j | junction temperature | | - | 125 | °C |
| T _{amb} | operating ambient temperature | | -65 | +125 | °C |

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ELECTRICAL CHARACTERISTICS

 T_{amb} = 25 °C unless otherwise specified.

| SYMBOL | PARAMETER | CONDITIONS | MAX. | UNIT |
|-----------------|-----------------------|---|------|------|
| V _F | forward voltage | see Fig.2 | | |
| | | I _F = 0.1 mA | 240 | mV |
| | | I _F = 1 mA | 320 | mV |
| | | I _F = 10 mA | 400 | mV |
| | | I _F = 30 mA | 500 | mV |
| | | I _F = 100 mA | 800 | mV |
| I_R | reverse current | V _R = 25 V; note 1; see Fig.3 | 2 | μΑ |
| t _{rr} | reverse recovery time | when switched from I_F = 10 mA to I_R = 10 mA; R_L = 100 Ω ; measured at I_R = 1 mA; see Fig.5 | 5 | ns |
| C _d | diode capacitance | $f = 1 \text{ MHz}$; $V_R = 1 \text{ V}$; see Fig.4 | 10 | pF |

Note

1. Pulse test: t_p = 300 μ s; δ = 0.02.

THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | CONDITIONS | VALUE | UNIT |
|---------------------|---|------------|-------|------|
| R _{th j-a} | thermal resistance from junction to ambient | note 1 | 315 | K/W |

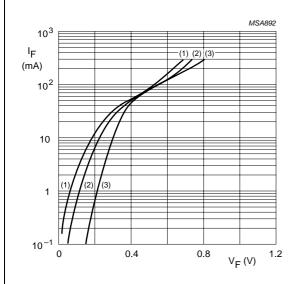
Note

1. Refer to SOD110 standard mounting conditions.

Schottky barrier diode

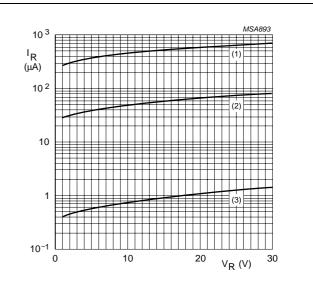
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GRAPHICAL DATA



- (1) $T_{amb} = 125 \, ^{\circ}C$.
- (2) $T_{amb} = 85 \, ^{\circ}C$.
- (3) $T_{amb} = 25 \, ^{\circ}C$.

Fig.2 Forward current as a function of forward voltage; typical values.



- (1) $T_{amb} = 125 \, ^{\circ}C$.
- (2) $T_{amb} = 85 \, ^{\circ}C$.
- (3) $T_{amb} = 25 \, ^{\circ}C$.

Fig.3 Reverse current as a function of reverse voltage; typical values.

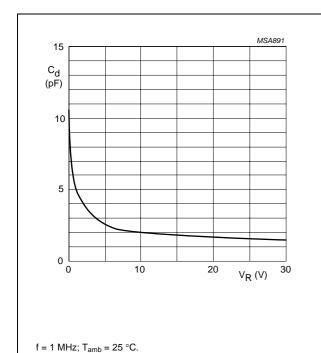
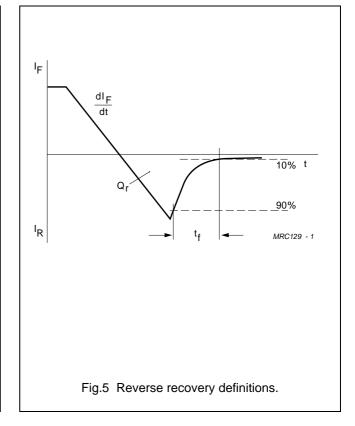


Fig.4 Diode capacitance as a function of reverse voltage; typical values.



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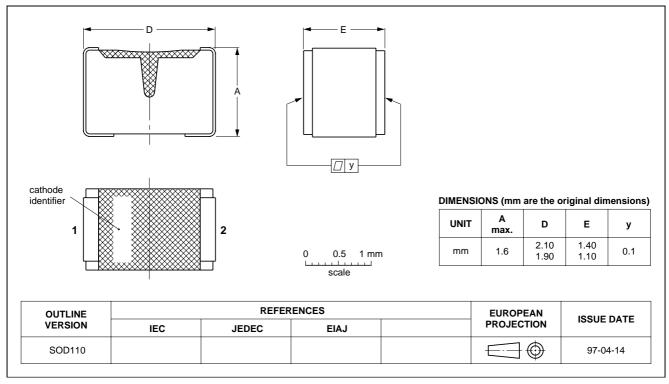
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PACKAGE OUTLINE

Very small ceramic rectangular surface mounted package

SOD110



Schottky barrier diode

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DATA SHEET STATUS

| DOCUMENT STATUS ⁽¹⁾ | PRODUCT STATUS ⁽²⁾ | DEFINITION |
|-----------------------------------|----------------------------------|---|
| Objective data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary data sheet | Qualification | This document contains data from the preliminary specification. |
| Product data sheet | Production | This document contains the product specification. |

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